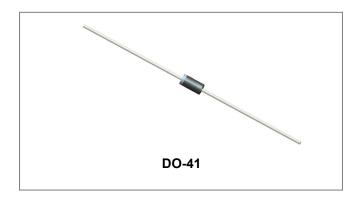


11DQ09 11DQ10

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# 11DQ09/11DQ10 SCHOTTKY RECTIFIER



### Features

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Maximum Ratings(limiting values, Tc =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	90(11DQ09) 100(11DQ10)	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>L</sub> =75°C, rectangular wave form On PC board 9mm <sup>2</sup> island	1.1	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	17	A

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 1 A, Pulse, TJ = 25 °C	0.76	0.85	V
		@ 2 A, Pulse, TJ = 25 °C	0.79	0.96	v
	V <sub>F2</sub>	@ 1 A, Pulse, T <sub>J</sub> = 125 °C	0.61	0.68	V
		@ 2 A, Pulse, TJ = 125 °C	0.65	0.78	v
Reverse Current*	I <sub>R1</sub>	$@V_R$ = Rated V <sub>R</sub> , Pulse, T <sub>J</sub> = 25 °C	0.1	0.5	mA
	I <sub>R2</sub>	@V <sub>R</sub> = Rated V <sub>R</sub> , Pulse, T <sub>J</sub> = 125 °C	0.05	10	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \degree C, f_{SIG} = 1MHz$	27	35	PF
Typical Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

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### Circuit Diagram





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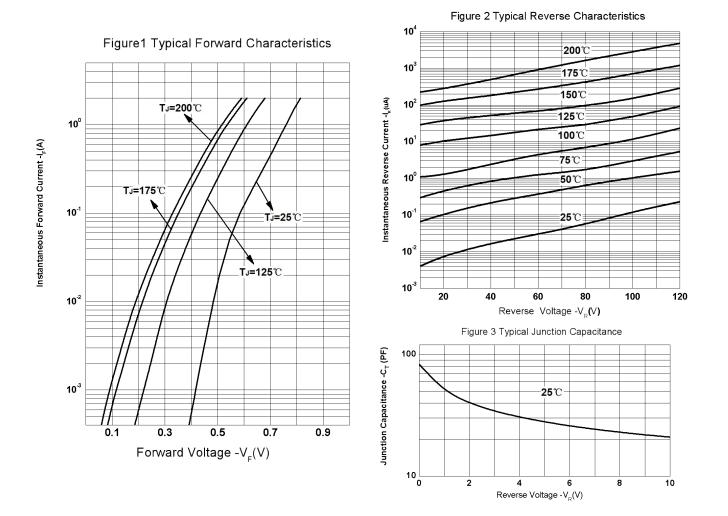
# 11DQ09 11DQ10

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### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-40 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-40 to +150	°C
Typical Thermal Resistance Junction to Ambient	R <sub>0JA</sub>	-	100	°C/W
Typical Thermal Resistance Junction to Lead	Rejl	-	81	°C/W
Approximate Weight	wt	-	0.34	g

### **Ratings and Characteristics Curves**



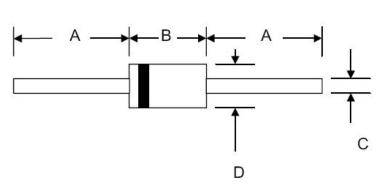


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## 11DQ09 11DQ10

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### **Mechanical Dimensions DO-41**



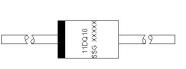
SYMDOL	Millim	neters	Inches	
SYMBOL	Min.	Max.	Min.	Max.
А	25.4	-	1.000	-
В	4.06	5.21	0.160	0.205
С	0.71	0.864	0.028	0.034
D	2.00	2.72	0.079	0.107

### **Ordering Information**

Device	Package	Shipping	
11DQ09 11DQ10	DO-41 (Pb-Free)	5000pcs /reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Marking Diagram**



Where XXXXX is YYWWL

- 11DQ10 = Part Name SSG
  - = SSG

YΥ

L

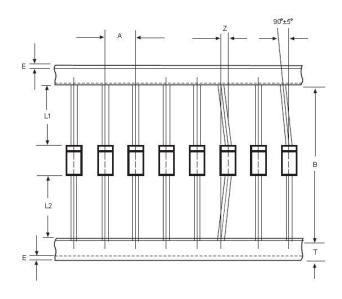
ww

= Year

= Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

### **Carrier Tape Specification DO-41**



SYMBOL	Millimeters		
	Min.	Max.	
A	4.50	5.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	

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